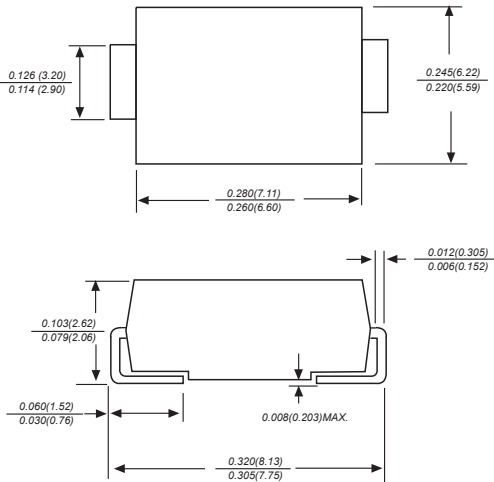


ES3A THRU ES3J

SURFACE MOUNT SUPER FAST RECTIFIER

Voltage - 50 to 600 Volts Forward Current - 3.0 Amperes

DO-214AB



Dimensions in inches and (millimeters)

FEATURES

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- For surface mounted applications
- Low reverse leakage
- Built-in strain relief, ideal for automated placement
- High forward surge current capability
- High temperature soldering guaranteed: 250°C/10 seconds at terminals
- Glass passivated chip junction
- RoHS Compliance
- Reach Compliance

MECHANICAL DATA

- Case:** JEDEC DO-214AB molded plastic body over passivated chip
- Terminals:** Solder plated, solderable per MIL-STD-750, Method 2026
- Polarity:** Color band denotes cathode end
- Mounting Position:** Any
- Weight:** 0.007 ounce, 0.25grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

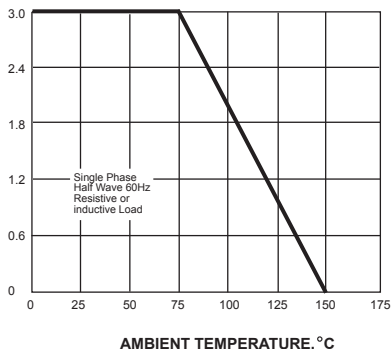
Ratings at 25°C ambient temperature unless otherwise specified.
 Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

	SYMBOLS	ES3A	ES3B	ES3C	ES3D	ES3E	ES3G	ES3J	UNITS
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	150	200	300	400	600	VOLTS
Maximum RMS voltage	V_{RMS}	35	70	105	140	210	280	420	VOLTS
Maximum DC blocking voltage	V_{DC}	50	100	150	200	300	400	600	VOLTS
Maximum average forward rectified current at $T_L=75^\circ C$	$I_{(AV)}$	3.0							Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	100.0							Amps
Maximum instantaneous forward voltage at 3.0A	V_F	0.95			1.25		1.7		Volts
Maximum DC reverse current $T_A=25^\circ C$ at rated DC blocking voltage $T_A=100^\circ C$	I_R	5.0			100.0				μA
Maximum reverse recovery time (NOTE 1)	t_{rr}	35							ns
Typical junction capacitance (NOTE 2)	C_J	45.0							pF
Typical thermal resistance (NOTE 3)	$R_{\theta JA}$	47.0							$^\circ C/W$
Operating junction and storage temperature range	T_J, T_{STG}	-65 to +150							$^\circ C$

- Note:**
- Reverse recovery condition $I_F=0.5A, I_R=1.0A, I_{rr}=0.25A$
 - Measured at 1MHz and applied reverse voltage of 4.0V D.C.
 - P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas

AVERAGE FORWARD RECTIFIED CURRENT,
AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



PEAK FORWARD SURGE CURRENT,
AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

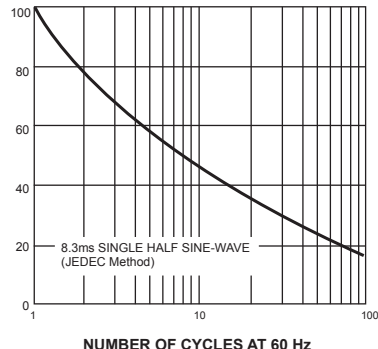


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

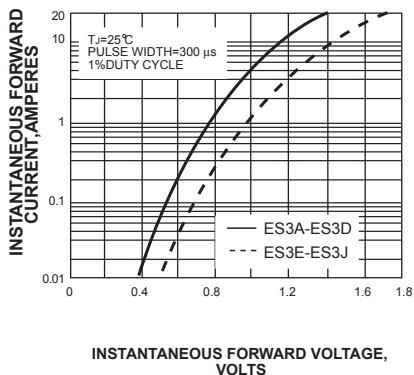


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

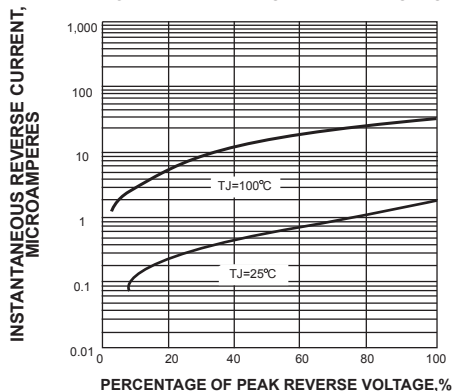
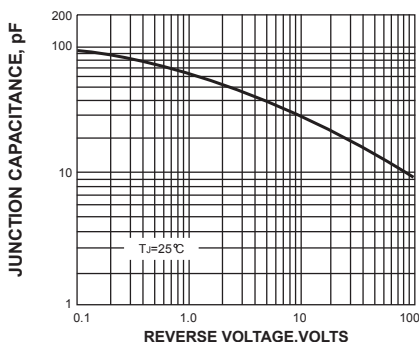


FIG. 5-TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE,
°C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE

